

FCP11N60N / FCPF11N60NT N-Channel SupreMOS[®] MOSFET 600 V, 10.8 A, 299 mΩ

Features

- R_{DS(on)} = 255 mΩ (Typ.) @ V_{GS} = 10 V, I_D = 5.4 A
- Ultra Low Gate Charge (Typ. Q_q = 27.4 nC)
- Low Effective Output Capacitance (Typ. C_{oss(eff.)} = 130 pF)
- 100% Avalanche Tested
- RoHS Compliant

Application

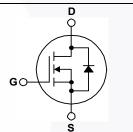
- LCD/LED/PDP TV
- Lighting
- Solar Inverter
- AC-DC Power Supply

GDS

Description

The SupreMOS[®] MOSFET is Fairchild Semiconductor's next generation of high voltage super-junction (SJ) technology employing a deep trench filling process that differentiates it from the conventional SJ MOSFETs. This advanced technology and precise process control provides lowest Rsp on-resistance, superior switching performance and ruggedness. SupreMOS MOSFET is suitable for high frequency switching power converter applications such as PFC, server/telecom power, FPD TV power, ATX power, and industrial power applications.





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol		Parameter	FCP11N60N	FCPF11N60NT	Unit		
V _{DSS}	Drain to Source Voltage		6	V			
V _{GSS}	Gate to Source Voltage			±30		V	
ID	Denie Current	- Continuous (T _C = 25 ^o C)	- Continuous (T _C = 25°C)		10.8*	٨	
	Drain Current	- Continuous ($T_C = 100^{\circ}C$)		6.8	6.8*	A	
I _{DM}	Drain Current	- Pulsed	(Note 1)	32.4	32.4*	Α	
E _{AS}	Single Pulsed Avalanche Energy			201.7		mJ	
AR	Avalanche Current		(Note 1)	3.7		А	
E _{AR}	Repetitive Avalanche Energy		(Note 1)	0.94		mJ	
dv/dt	MOSFET dv/dt			100		V/ns	
uv/ut	Peak Diode Recovery dv/dt			20		V/ns	
P _D	Dower Dissinction	(T _C = 25°C)		94.0	32.1	W	
	Power Dissipation	- Derate Above 25°C	- Derate Above 25°C		0.26	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature Range			-55 to	°C		
ΓL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds			3	°C		

*Drain current limited by maximum junction temperature.

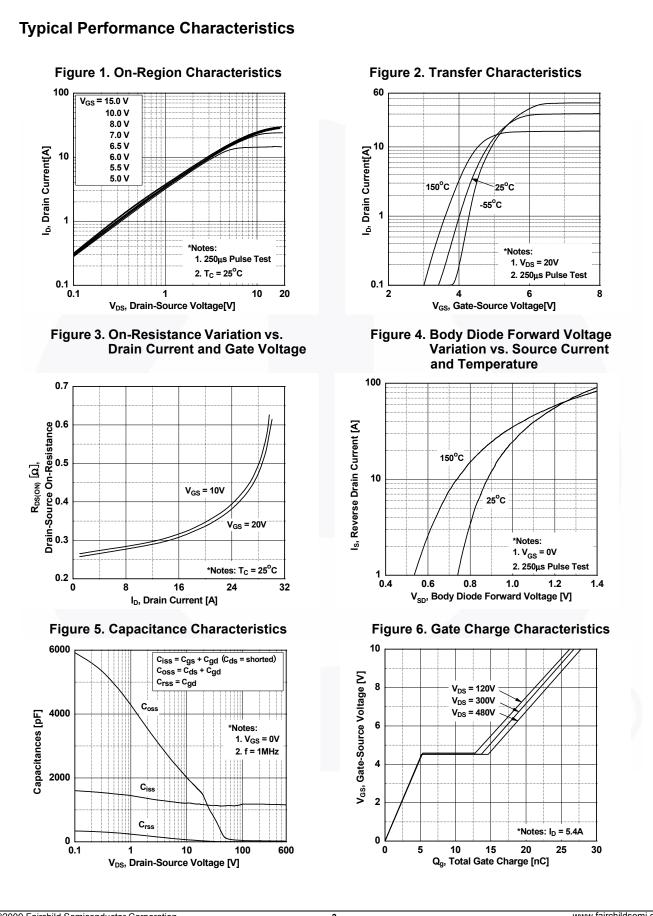
Thermal Characteristics

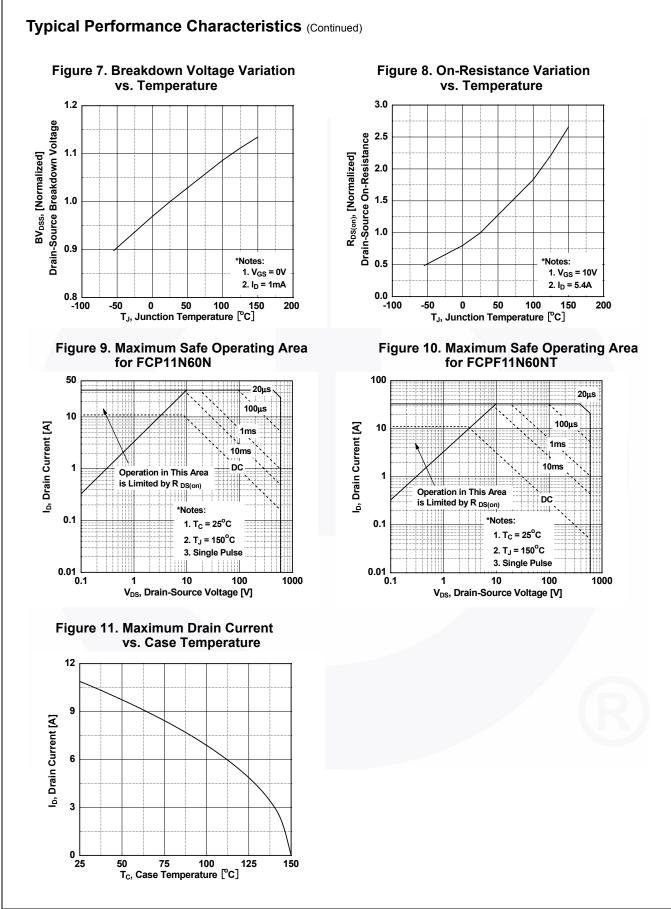
Symbol	Parameter	FCP11N60N	FCPF11N60NT	Unit
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	1.33	3.9	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient, Max.	62.5	62.5	-0/10

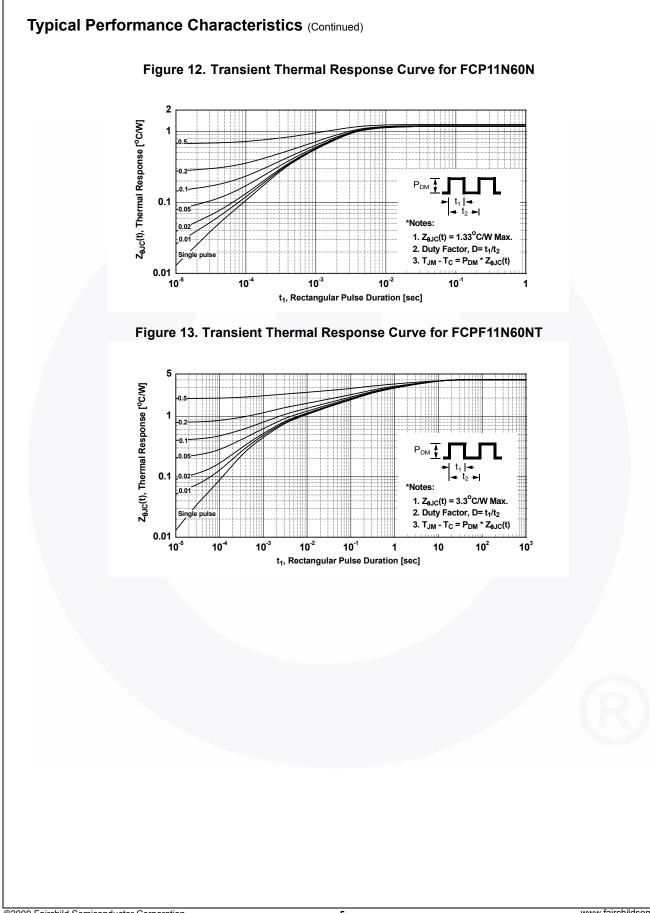
November 2013

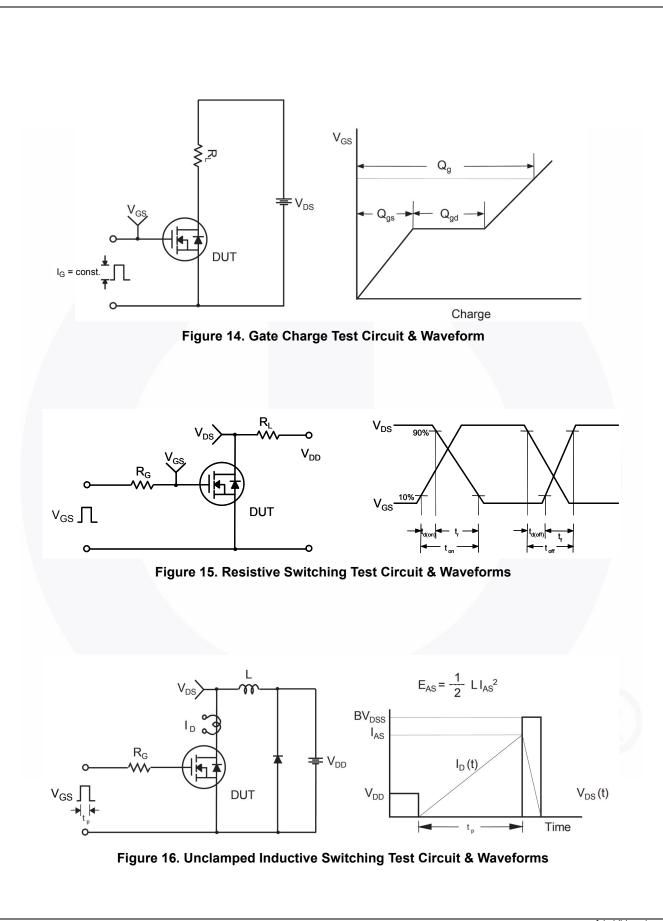
FCPF11N		FCP11N60N		kage	Packing Method	Reel Size	Ia	pe Width	Guu	Intity
	60NT			-220	Tube	N/A		N/A	50 units	
Electrica			TO-2	220F Tube N/A			N/A		50 units	
	I Char	acteristics T _C = 2	25°C unle	ess othe	erwise noted.					
Symbol		Parameter			Test Condition	าร	Min.	Тур.	Max.	Unit
Off Charac	teristic	S								
BV _{DSS}		Source Breakdown Vol	tage	In	= 1 mA, V _{GS} = 0 V, T _C	$= 25^{\circ}C$	600	-	_	V
ABV _{DSS}		akdown Voltage Temperature					000			
/ ΔTJ Coeffi				ID	$I_D = 1 \text{ mA}$, Referenced to 25° C			0.73	-	V/ºC
				V	V _{DS} = 480 V, V _{GS} = 0 V		-	-	10	
DSS	Zero Gate Voltage Drain Current		nt	V	$V_{DS} = 480 \text{ V}, V_{GS} = 0 \text{ V}, T_{C} = 125^{\circ}\text{C}$		-	-	100	μA
GSS	Gate to	Gate to Body Leakage Current		V _{GS} = ±30 V, V _{DS} = 0 V			-	-	±100	nA
On Charac	teristics	5								
V _{GS(th)}		reshold Voltage		V	_{GS} = V _{DS} , I _D = 250 μA		2.0	-	4.0	V
RDS(on)		rain to Source On Resis	stance	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 5.4 \text{ A}$ $V_{DS} = 40 \text{ V}, \text{ I}_{D} = 5.4 \text{ A}$			-	0.255 13.5	0.299	Ω S
9FS	Forward	d Transconductance	_							
Dynamic C	haracte	pristics								1
C _{iss}		nput Capacitance						1130	1505	pF
C _{oss}		Output Capacitance			V _{DS} = 100 V, V _{GS} = 0 V,			45	60	pF
C _{rss}	-	e Transfer Capacitance	-	f =	f = 1 MHz		-	3	5	pF
C _{oss}		Output Capacitance Effective Output Capacitance		V _{DS} = 380 V, V _{GS} = 0 V, f = 1 MHz			-	25	-	pF
Coss(eff.)				$V_{DS} = 0 V \text{ to } 480 V, V_{GS} = 0 V$			-	130	-	pF
$Q_{g(tot)}$		Total Gate Charge at 10V					-	27.4	35.6	nC
Q_{gs}		Source Gate Charge		-	V _{DS} = 380 V, I _D = 5.4 A, V _{GS} = 10 V		-	4.9	-	nC
Q _{gd}		Drain "Miller" Charge			33 10 1	(Note 4)	-	8.8	-	nC
ESR	Equivalent Series Resistance (G-S)		G-S)	f = 1 MHz			-	2.0	-	Ω
Switching	Charact	teristics				I				
d(on)		Delay Time						13.6	37.2	ns
		Rise Time		Vr	V _{DD} = 380 V, I _D = 5.4 A,			9.1	28.2	ns
d(off)	Turn-Off Delay Time			-V.	$V_{GS} = 10 \text{ V}, \text{ R}_{G} = 4.7 \Omega$			42.0	94.0	ns
d(off) f		Fall Time			(Note 4)			10.0	30.0	ns
						(100 1)			00.0	
		le Characteristics							10.0	
S		m Continuous Drain to S					-	-	10.8	A
SM		m Pulsed Drain to Source						-	32.4	A
/ _{SD}		Source Diode Forward	voltage		$V_{GS} = 0 V, I_{SD} = 5.4 A$			-	1.2	V
n N		Recovery Time Recovery Charge			_{GS} = 0 V, I _{SD} = 5.4 A, _F /dt = 100 A/μs		-	268 3.1		ns
2 ^m	Reveise	Recovery Charge		u	μαι – 100 Αγμο		-	3.1	-	μC

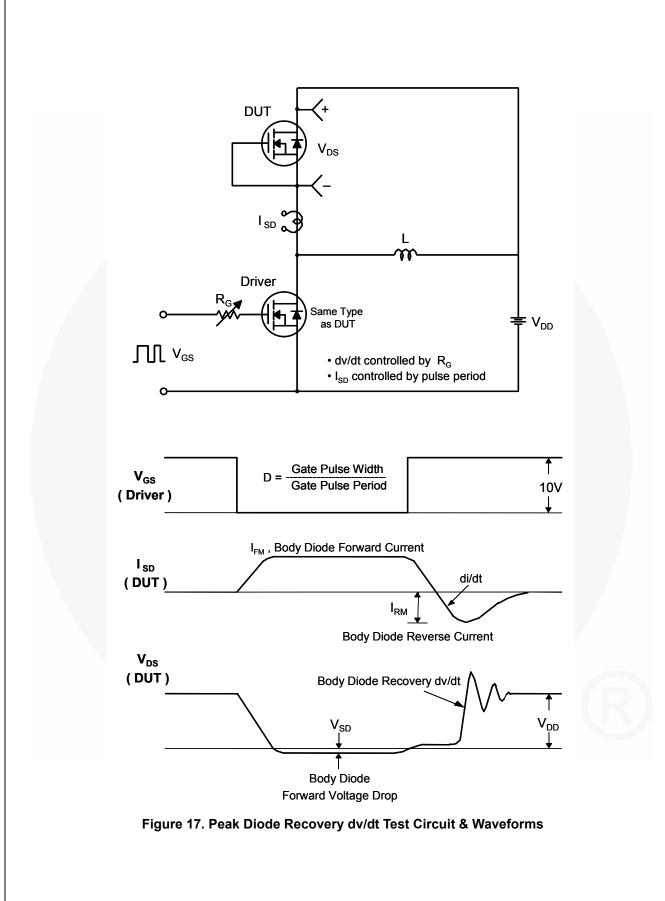
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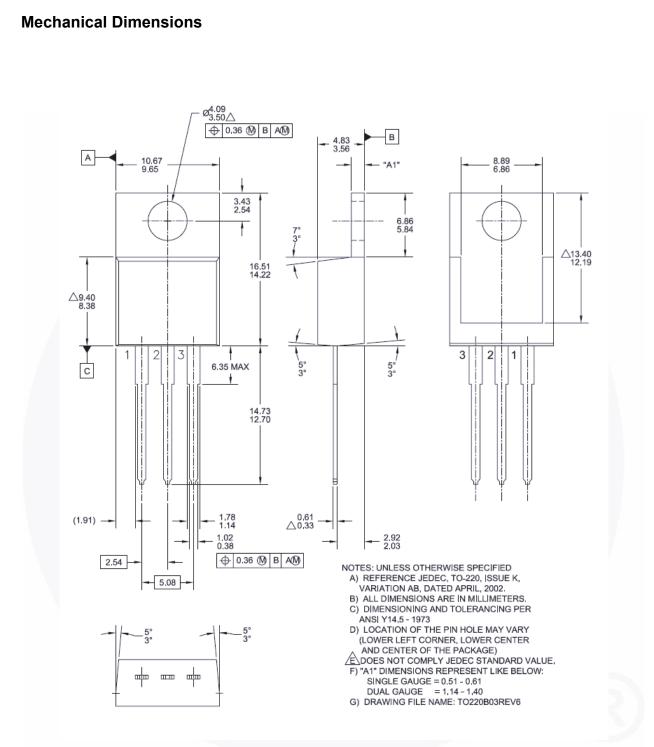
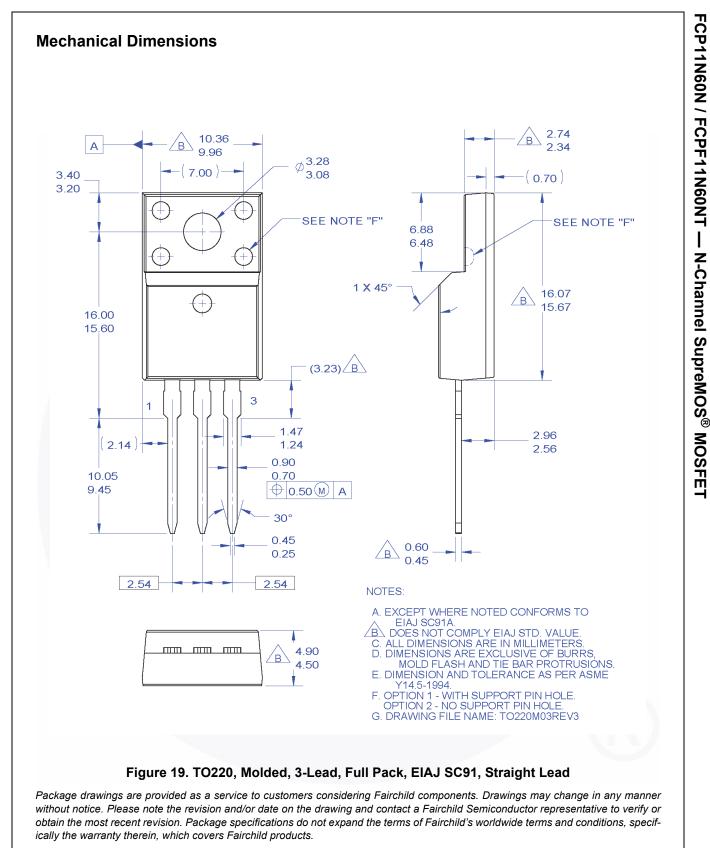


Figure 18. TO-220, Molded, 3-Lead, Jedec Variation AB

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F-PES™

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